

Data sheet acquired from Harris Semiconductor SCHS024C – Revised October 2003

CMOS 8-Stage Static Shift Registers

High-Voltage Types (20-Volt Rating) CD4014B:

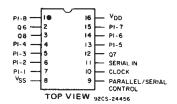
Synchronous Parallel or Serial Input/Serial Output

CD4021B:

Asynchronous Parallel Input or Synchronous Serial Input/Serial Output

■ CD4014B and CD4021B series types are 8-stage parallel- or serial-input/serial output registers having common CLOCK and PARALLEL/SERIAL CONTROL inputs, a single SERIAL data input, and individual parallel "JAM" inputs to each register stage. Each register stage is a D-type, master-slave flip-flop. In addition to an output from stage 8, "Q" outputs are also available from stages 6 and 7. Parallel as well as serial entry is made into the register synchronously with the positive clock line transition in the CD4014B. In the CD4021B serial entry is synchronous with the clock but parallel entry is asynchronous. In both types, entry is controlled by the PARALLEL/SERIAL CONTROL input. When the PARALLEL/SERIAL CON-TROL input is low, data is serially shifted into the 8-stage register synchronously with the positive transition of the clock line. When the PARALLEL/SERIAL CONTROL input is high, data is jammed into the 8-stage register via the parallel input lines and synchronous with the positive transition of the clock line. In the CD4021B, the CLOCK input of the internal stage is "forced" when asynchronous parallel entry is made. Register expansion using multiple packages is permitted.

The CD4014B and CD4021b series types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, MT, and NSR suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

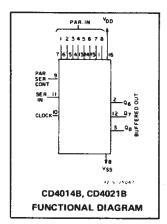


TERMINAL DIAGRAM CD4014B, CD4021B

CD4014B, CD4021B Types

Features:

- Medium-speed operation . . . 12 MHz (typ.) clock rate at VDD-VSS = 10 V
- Fully static operation
- 8 master-slave flip-flops plus output buffering and control gating
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μA at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (full package-temperature range) = 1 V at V_{DD} = 5 V
 2 V at V_{DD} = 10 V
 2.5 V at V_{DD} = 15 V
- Standardized, symmetrical output characteristics
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative
 Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"



Applications:

- Parallel input/serial output data queueing
- Parallel to serial data conversion
- General-purpose register

RECOMMENDED OPERATING CONDITIONS AT $T_A = 25^{\circ}$ C, Unless Otherwise Specified For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

CHARACTERISTIC	v _{DD}	LIN	MITS	UNITS
	(V)	Min.	Max.	OMITS
Supply-Voltage Range (T _A = Full Package-Temperature Range)		3	18	v
Clock Pulse Width, t _W	5 10 15	180 80 50	- - -	ns
Clock Frequency, f _{CL}	5 10 15	_ _ _	3 6 8.5	MHz
Clock Rise and Fall Time, t _F CL, t _f CL	5 10 15	_ _ ~	15 15 15	μs
Set-up Time, t _s : Serial Input (ref. to CL)	5 10 15	120 80 60	_ _ _	ns
Parallel Inputs CD4014B (ref. to CL)	5 10 15	80 50 40	- -	ns
Parallel Inputs CD4021B (ref. to P/S)	5 10 15	50 30 20	_ _ _	ns
Parallel/Serial Control CD4014B (ref. to CL)	5 10 15	180 80 60	- - -	ns
Parallel/Serial Pulse Width, t _W (CD4021B)	5 10 15	160 80 50	<u>-</u> `·	ns
Parallel/Serial Removal Time, †REM (CD4021B)	5 10 15	280 140 100	_ _ _	ns

CD4014B, CD4021B Types

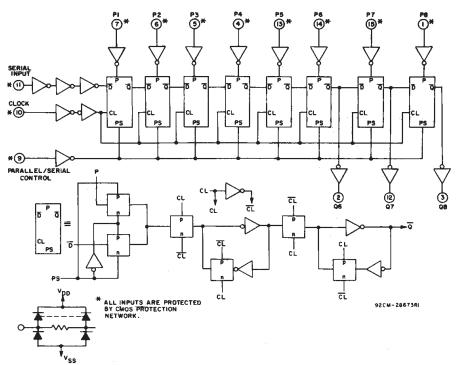


Fig. 1 - Logic diagram for CD4014B.

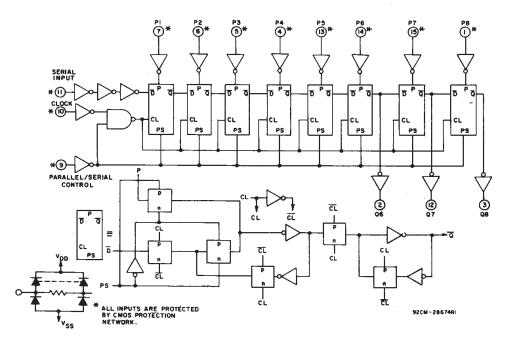


Fig. 2 - Logic diagram for CD40218.

TRUTH TABLE - CD4021B

CL	Serial Input	Parallel/ Serial Control	PI-1	Pl∙n	Q ₁ (Internal)	an
х	×	1	0	0	0	0
х	х	1	0	1	0	1
Х	х	1	1	0	1	0
х	х	1	1	1	1	1
<u></u>	0	0	х	х	0	Q _n 1
$\underline{\mathcal{L}}$	1	0	х	x	1	Q _n -1 Q _n -1
_	х	0	х	х	Ω1	an
			X = DO	N'T CA	RE CASE	

CD4014B, CD4021B Types.

MAXIMUM RATINGS, Absolute-Maximum Values:	
DC SUPPLY-VOLTAGE RANGE, (VDD)	1 Sec. 10 1
Voltages referenced to VSS Terminal)	0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS	+0.5V
DC INPUT CURRENT, ANY ONE INPUT	±10mA
POWER DISSIPATION PER PACKAGE (PD):	
For T _A = -55°C to +100°C	500mW-
For T _A = +100°C to +125°C Derait DEVICE DISSIPATION PER OUTPUT TRANSISTOR	e Linearity at 12mW/°C to 200mW
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types	s)100mW
OPERATING-TEMPERATURE RANGE (TA)	55°C to +125°C
STORAGE TEMPERATURE RANGE (Tatg). LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 \pm 1/32 inch (1.59 \pm 0.79mm) from case for 10s max	+265°C

TATION	ECTRICAL	 	المالمكتاب

CHARAC- TERISTIC	CON	DITIO	NS	LI	MITS AT	INDICA	TED TEI	MPERA	FURES (°C)	UNIT
	Vo	VIN	v _{DD}						+25		S
	(V)	(V)	(V)	-55	–40	+85	+125	Min.	Тур.	Max.	
Quiescent		0,5	5	5	5	150	150		0.04	5	
Device		0,10	10	10	10	300	300		0.04	10	μA
Current, IDD Max.		0,15	15	20	20	600	600	_	0.04	20	ľ
		0,20	20	100	100	3000	3000	_	0.08	100	
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	-	
(Sink) Current	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	-	
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	_	
Output High	4.6	0,5	5	-0.64	-0.61	-0,42	-0.36	-0.51	-1	_	mΑ
(Source)	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	_	
Current, IOH Min.	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	_	
OH Min.	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	-	
Output Voltage:		0,5	5		0.	_	0	0.05			
Low-Level,	seri.	0,10	.10		0.	_	0	0.05			
VOL Max.	_	0,15	15		0.	05		-	0	0.05	l v
Output	<u> </u>	0,5	5		4.	95		· 4.95	-5	_	
Voltage: High-Level,		0,10	10		9.	95		9.95	10	_	
VOH Min.	_	0,15	15		14.	95		14.95	15		
Input Low	0.5,4.5		5			1.5		-	_	1.5	
Voltage	1,9		10			3		_		3	
V _{IL} Max.	1.5,13.5	_	15			4		-	_	4	v
Input High	0.5,4.5	_	5		3	3.5		3.5	_		
Voltage,	1,9	_	10			7		7	_	_	
V _{IH} Min.	1.5,13.5	-	15			11		11	_	_	
Input Current I _{IN} Max.	_	0,18	18	±0.1	±0.1	±1	±1	1	±10 ⁻⁵	±0.1	μΑ

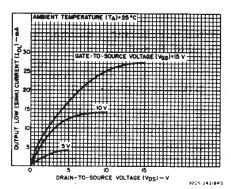


Fig. 3 — Typical output low (sink) current characteristics.

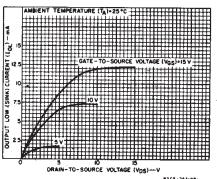


Fig. 4 – Minimum output low (sink) current characteristics.

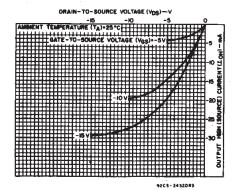


Fig. 5 — Typical output high (source) current characteristics.

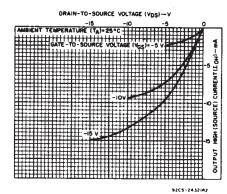


Fig. 6 — Minimum output high (source) current characteristics.

CD4014B, CD4021B Types

DYNAMIC ELECTRICAL CHARACTERISTICS at T_A=25°C, Input $\rm t_r, t_f$ =20 ns, C_=50 pF, R_1=200 K Ω

	CONI	EST DITIONS		LIMIT	s	
CHARACTERISTIC		(V)	Min.	Тур.	Max.	UNITS
Propagation Delay Time,		- 5	_	160	320	
tPLH, tPHL	1	10	-	80	160	ns
PLH, PHL		15	_	60	120	
Transition Time.		5		100	200	
tTHL, tTLH		10	-	50	100	ns
THEFTER		15		40	80	
Maximum Clock Input	1	5	3	6	_	
Frequency, f _{CL}	1	10	6	12	_	MHz
- reduction, ICE	1	15	8.5	17	_	
Minimum Clock Pulse		. 5		90	180	
Width, tw		10	-	40	80	ns
···otii, tw		15		25	50	
Clock Rise and Fall Time,		5	_	_	15	
t _r CL, t _f CL*		10		_	15	μs
<u> </u>		15		_	15	<u>'</u>
Minimum Set-up Time, ts:		5		60	120	
Serial Input		10	-	40	80	ns
(ref. to CL)		15		30	60	
Parallel Inputs		5	_	40	80	
CD4014B	ĺ	10	_	25	50	ns
(ref. to CL)		15	,	20	40	
Parallel Inputs		5		25	50	
CD4021B		10	_	15	30	ns
(ref. to P/S)		15	_	10	20	
Parallel/Serial Control		5	_	90	180	
CD4014B		10	-	40	80	ns
(ref. to CL)		15	_	30	60	
Minimum Hold Time, tH:		5	_		0	
Serial In, Parallel In,		10	_	_	0	ns
Parallel/Serial Control		15	_	_	0	
Minimum P/S Pulse Width,		5	_	80	160	
tWH		10	-	40	80	ns
(CD4021B)		15	-	25	50	
Minimum P/S Removal Time,		5		140	280	
^t REM		10	_	70	140	ns
CD4021B (ref. to CL)		15	- `	50	100	
Average Input Capacitance, C	Any	Input	_	5	7.5	ρF

^{*} If more than one unit is cascaded t_rCL should be made less than or equal to the sum of the transition time and the fixed propagation delay of the output of the driving stage for the estimated capacitive load.

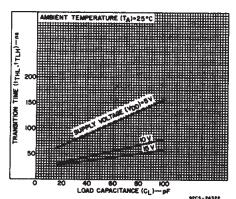


Fig. 7 — Typical transition time as a function of load capacitance.

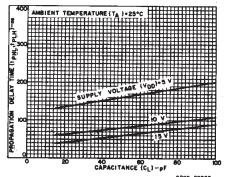


Fig. 8 — Typical propagation delay time as a function of load capacitance.

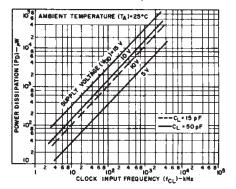


Fig. 9 — Typical dynamic power dissipation as a function of clock input frequency.

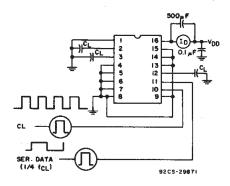


Fig. 10 - Dynamic power dissipation test circuit.

CD4014B, CD4021B Types

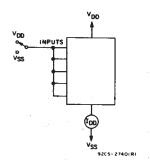


Fig. 11 — Quiescent device current test circuit.

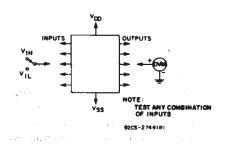


Fig. 12 - Input voltage test circuit.

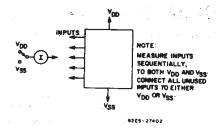
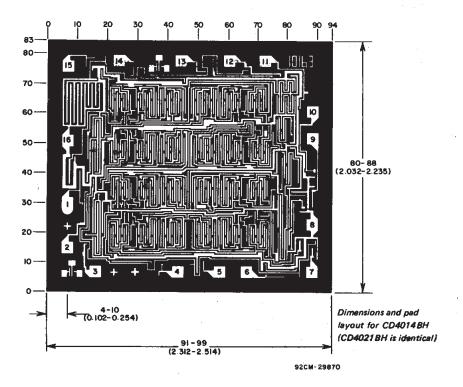


Fig. 13 - Input current test circuit.



Dimensions in perentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).



PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CD4014BE	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4014BEE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4014BF3A	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
CD4014BM	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BM96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BM96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BM96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BMG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BMT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BMTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BMTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BNSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BNSRE4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BNSRG4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BPWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BPWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BPWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BE	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4021BEE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4021BF	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
CD4021BF3A	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
CD4021BF3AS2283	OBSOLETE	CDIP	J	16		TBD	Call TI	Call TI
CD4021BM	ACTIVE	SOIC	D	16	40	Green (RoHS &	CU NIPDAU	Level-1-260C-UNLIM





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Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	n MSL Peak Temp ⁽³⁾
						no Sb/Br)		
CD4021BM96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BM96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BM96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BMG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BMT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BMTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BMTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BNSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BNSRE4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BNSRG4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BPWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BPWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BPWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
JM38510/05754BEA	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



PACKAGE OPTION ADDENDUM

14-Oct-2008

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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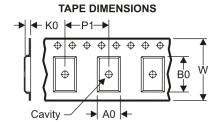




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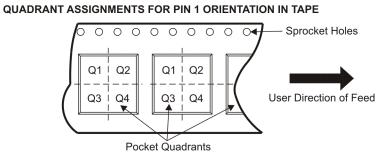
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

— Reel Width (WT)



*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4014BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4014BNSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4014BPWR	TSSOP	PW	16	2000	330.0	12.4	7.0	5.6	1.6	8.0	12.0	Q1
CD4021BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4021BNSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4021BPWR	TSSOP	PW	16	2000	330.0	12.4	7.0	5.6	1.6	8.0	12.0	Q1





*All dimensions are nominal

All difficultions are florifinal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4014BM96	SOIC	D	16	2500	333.2	345.9	28.6
CD4014BNSR	SO	NS	16	2000	346.0	346.0	33.0
CD4014BPWR	TSSOP	PW	16	2000	346.0	346.0	29.0
CD4021BM96	SOIC	D	16	2500	333.2	345.9	28.6
CD4021BNSR	SO	NS	16	2000	346.0	346.0	33.0
CD4021BPWR	TSSOP	PW	16	2000	346.0	346.0	29.0

PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

D (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AC.



D(R-PDSO-G16)



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC—7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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